

# Automotive-grade high voltage ignition coil driver NPN power Darlington transistor

Datasheet - production data

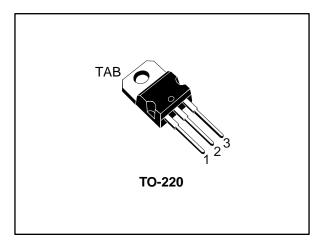
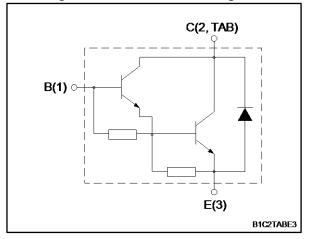


Figure 1: Internal schematic diagram



#### **Features**



- AEC-Q101 qualified
- Very rugged Bipolar technology
- High operating junction temperature

#### **Applications**

• High ruggedness electronic ignitions

#### **Description**

This is a high voltage power Darlington transistor developed using multi-epitaxial planar technology. It has been properly designed for automotive environment as electronic ignition power actuators.

**Table 1: Device summary** 

Order code	Marking	Package	Packing
BU931T	BU931T	TO-220	Tube

Contents BU931T

## **Contents**

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BU931T Electrical ratings

# 1 Electrical ratings

Table 2: Absolute maximum ratings

Symbol	Parameter	Value	Unit
Vces	Collector-emitter voltage (V <sub>BE</sub> = 0)	500	V
V <sub>CEO</sub>	Collector-emitter voltage (I <sub>B</sub> = 0)	400	V
V <sub>EBO</sub>	Emitter-base voltage (Ic = 0)	5	V
Ic	Collector current	10	Α
I <sub>CM</sub>	Collector peak current	20	Α
lΒ	Base current	1	Α
Івм	Base peak current	5	Α
Ртот	Total dissipation at Tc = 25 °C	125	W
T <sub>stg</sub>	Storage temperature range	CE to 475	°C
Tj	Operating junction temperature range	-65 to 175 °C	

Table 3: Thermal data

Symbol	Parameter	Value	Unit
RthJC	Thermal resistance junction-case	1.2	°C/W
R <sub>thJA</sub>	Thermal resistance junction-ambient	62.5	°C/W

Electrical characteristics BU931T

## 2 Electrical characteristics

(T<sub>C</sub> = 25 °C unless otherwise specified)

**Table 4: Electrical characteristics** 

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
	Collector cut-off	V <sub>BE</sub> = 0 V, V <sub>CE</sub> = 500 V		-	100	μA
ICES	current	$V_{BE} = 0 \text{ V}, V_{CE} = 500 \text{ V},$ $T_{C} = 125 ^{\circ}\text{C}^{(1)}$		-	0.5	mA
	Collector cut-off	I <sub>B</sub> = 0 A, V <sub>CE</sub> = 450 V		-	100	μΑ
ICEO	current	I <sub>B</sub> = 0 A, V <sub>CE</sub> = 450 V, T <sub>C</sub> = 125 °C <sup>(1)</sup>		-	0.5	mA
I <sub>EBO</sub>	Emitter cut-off current	I <sub>C</sub> = 0 A, V <sub>EB</sub> = 5 V		-	20	mA
V <sub>CEO(sus)</sub> <sup>(2)</sup>	Collector-emitter sustaining voltage	I <sub>B</sub> = 0 A, I <sub>C</sub> = 100 mA	400	-		V
	Collector-emitter saturation voltage	Ic = 7 A, I <sub>B</sub> = 70 mA		-	1.6	V
V <sub>CE(sat)</sub> <sup>(2)</sup>		Ic = 8 A, I <sub>B</sub> = 100 mA		-	1.8	V
		Ic = 10 A, I <sub>B</sub> = 250 mA		-	1.8	V
	_	$I_C = 7 \text{ A}, I_B = 70 \text{ mA}$		-	2.2	V
V <sub>BE(sat)</sub> <sup>(2)</sup>	Base-emitter saturation voltage	Ic = 8 A, I <sub>B</sub> = 100 mA		-	2.4	V
	odiaration voltage	I <sub>C</sub> = 10 A, I <sub>B</sub> = 250 mA		-	2.5	V
h <sub>FE</sub> <sup>(2)</sup>	DC current gain	Ic = 5 A, V <sub>CE</sub> = 10 V	300	-		
VF	Diode forward voltage	I <sub>F</sub> = 10 A		-	2.5	V
	Functional test	V <sub>CC</sub> = 24 V,L = 7 mH, V <sub>clamp</sub> = 400 V (see <i>Figure 10: "Functional test circuit"</i> )	8	-		А

#### Notes:

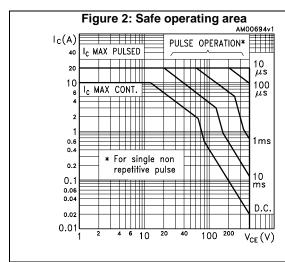
Table 5: Inductive load switching times

		<u> </u>				
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
ts	Storage time	V <sub>CC</sub> = 12 V, V <sub>clamp</sub> = 300 V, L = 7 mH,	-	15	-	μs
t <sub>f</sub>	Fall time	$R_{BE} = 47 \Omega, I_{C} = 7 A, I_{B} = 70 \text{ mA}$	-	0.5	-	μs

<sup>&</sup>lt;sup>(1)</sup>Defined by design, not subject to production test.

 $<sup>^{(2)}\</sup>text{Pulse}$  test: pulse duration ≤ 300 µs, duty cycle ≤ 2 %.

## 2.1 Electrical characteristics (curves)



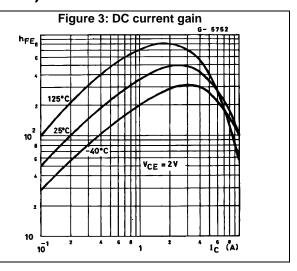


Figure 4: Switching time inductive load

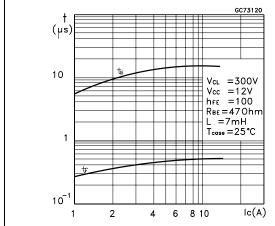


Figure 5: Collector-emitter saturation voltage

@ hFE = 50

VCE(sat)

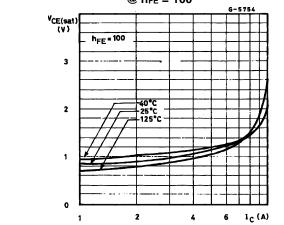
hFE=50

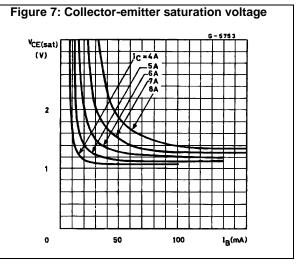
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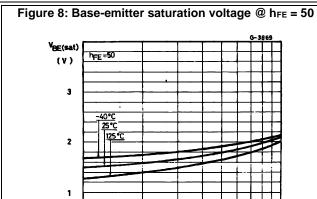
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Figure 6: Collector-emitter saturation voltage
@ hfe = 100





0

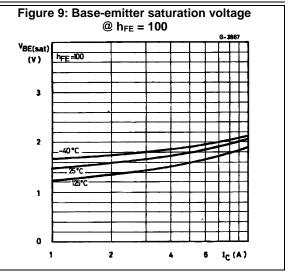


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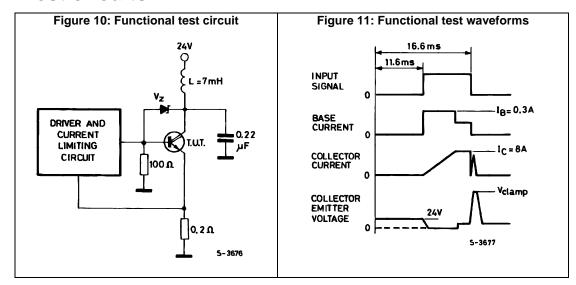
I<sub>C</sub> (A)

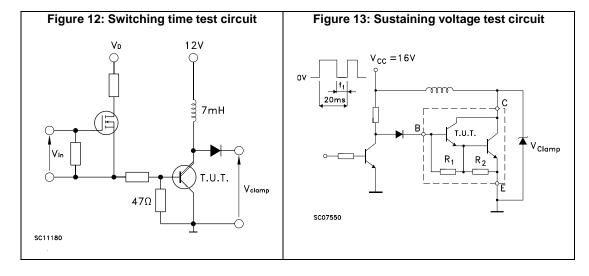
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BU931T Test circuits

#### 3 Test circuits





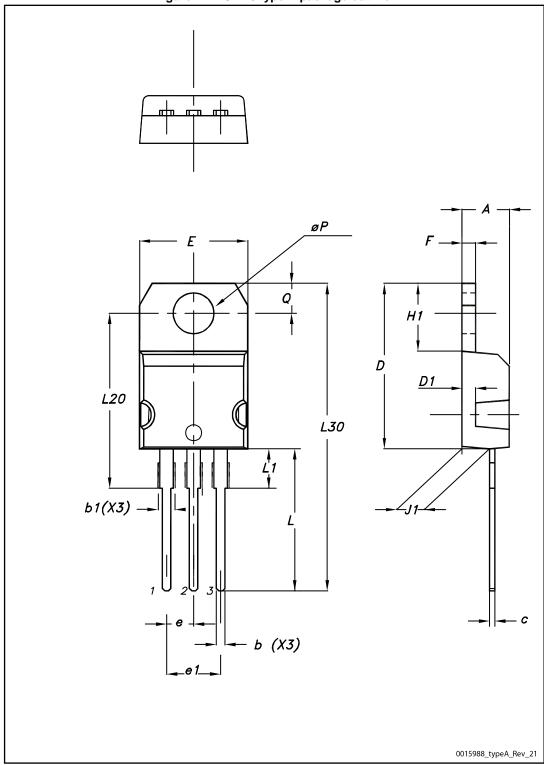
## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

BU931T Package information

# 4.1 TO-220 type A package information

Figure 14: TO-220 type A package outline



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Table 6: TO-220 type A package mechanical data

		mm	
Dim.	Min.	Тур.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.55
С	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10.00		10.40
е	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13.00		14.00
L1	3.50		3.93
L20		16.40	
L30		28.90	
øΡ	3.75		3.85
Q	2.65		2.95

BU931T Revision history

# 5 Revision history

Table 7: Document revision history

Date	Revision	Changes
18-Nov-2008	3	Package changed from TO-218 to TO-247 for BU931P. Inserted type in TO-220 (BU931T).
02-Dec-2009	4	Modified I <sub>C</sub> test condition value of V <sub>CEO(sus)</sub> parameter <i>Table 4 on page 4</i> , updated TO-220 package mechanical data.
12-Oct-2017	5	The part numbers BU931 and BU931P have been moved to two separate datasheets.  Modified Table 2: "Absolute maximum ratings", Table 3: "Thermal data" and Table 4: "Electrical characteristics".  Updated Section 4: "Package information".  Minor text changes.

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